



PRELIMINARY

# SOLID STATE DEVICES, INC.

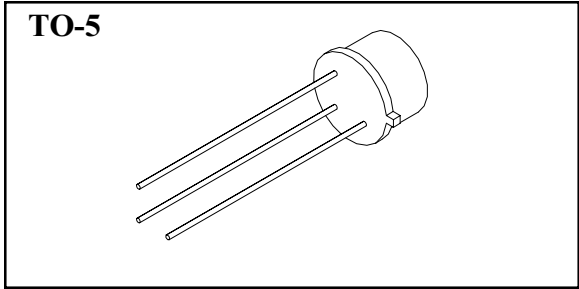
14005 Stage Road \* Santa Fe Springs, Ca 90670  
Phone: (562) 404-4474 \* Fax: (562) 404-1773

## DESIGNER'S DATA SHEET

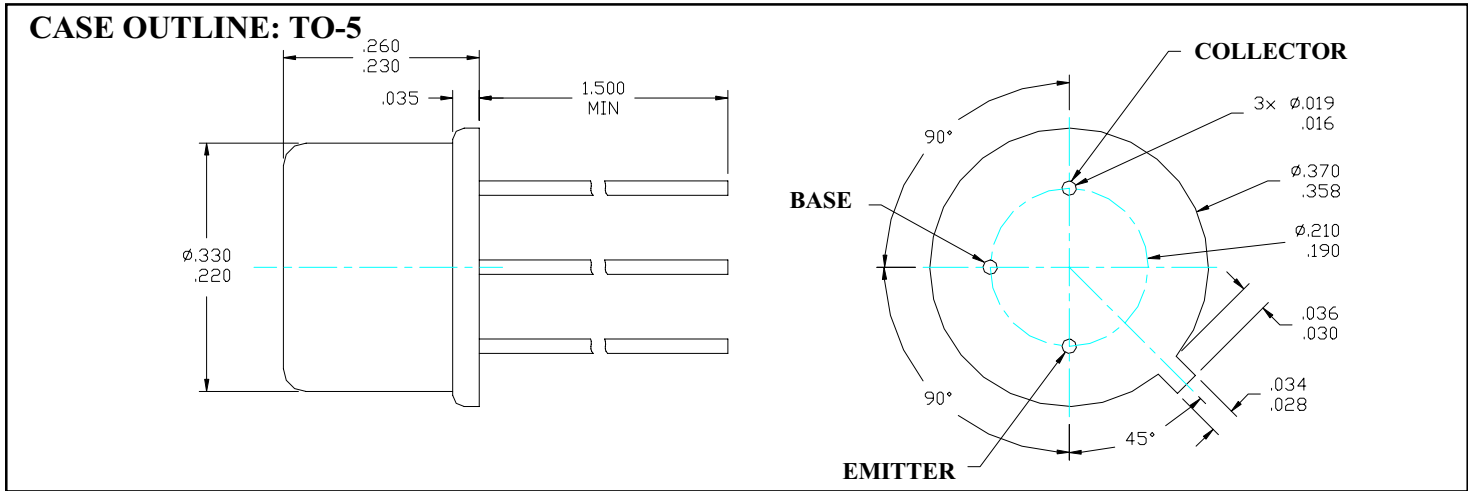
- FEATURES:**
- **$V_{CEO}$  400V.**
  - **Fast Switching.**
  - **Very Low Leakage.**
  - **Low Saturation Voltage.**
  - **200°C Operating, Gold Eutectic Die Attach.**
  - **Designed for Complementary Use with SFT1192.**

# SFT6800

## 2 AMP 500 VOLTS NPN TRANSISTOR



MAXIMUM RATINGS	SYMBOL	VALUE	UNITS
Collector-Emitter Voltage	$V_{CEO}$	400	Volts
Collector-Base Voltage	$V_{CBO}$	500	Volts
Emitter-Base Voltage	$V_{EBO}$	10	Volts
Collector Current	$I_C$	2	Amps
Base Current	$I_B$	0.5	Amps
Total Device Dissipation @ $T_C=100^\circ\text{C}$ Derate above 100°C	$P_D$	6.67 150	W mW/°C
Operating and Storage Temperature	$T_J, T_{STG}$	-65 to +200	°C
Thermal Resistance, Junction to Case	$R_{\theta JC}$	15	°C/W



**NOTE:** All specifications are subject to change without notification. SCD's for these devices should be reviewed by SSDI prior to release.

**DATA SHEET #: TR0005B**

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ELECTRICAL CHARACTERISTICS		SYMBOL	MIN	MAX	UNITS
Collector-Emitter Breakdown Voltage ( $I_C = 20\text{mA}_{DC}$ )		$BV_{CEO}$	400	-	V
Collector-Base Breakdown Voltage ( $I_C = 100\mu\text{A}_{DC}$ )		$BV_{CBO}$	500	-	V
Emitter-Base Breakdown Voltage ( $I_E = 20\mu\text{A}_{DC}$ )		$BV_{EBO}$	10	-	V
Collector Cutoff Current ( $V_{CB} = 400\text{V}_{DC}$ )		$I_{CBO}$	-	200	nA
Collector Cutoff Current ( $V_{CE} = 400\text{V}_{DC}$ , $V_{EB} = 1.5\text{V}_{DC}$ )		$I_{CEV}$	-	200	nA
Emitter Cutoff Current ( $V_{EB} = 6\text{V}_{DC}$ )		$I_{EBO}$	-	200	nA
DC Current Gain* ( $V_{CE} = 5\text{V}_{DC}$ )					
	( $I_C = 50\text{mA}_{DC}$ )		50	-	
	( $I_C = 500\text{mA}_{DC}$ )	$H_{FE}$	40	-	
	( $I_C = 1.0\text{A}_{DC}$ )		15	-	
Collector-Emitter Saturation Voltage* ( $I_C = 500\text{mA}_{DC}$ , $I_B = 50\text{mA}_{DC}$ )		$V_{CE(SAT)}$	-	500	mV <sub>DC</sub>
Base-Emitter Saturation Voltage* ( $I_C = 500\text{mA}_{DC}$ , $I_B = 50\text{mA}_{DC}$ )		$V_{BE(SAT)}$	-	1.0	V <sub>DC</sub>
Current Gain Bandwidth Product ( $I_C = 50\text{mA}_{DC}$ , $V_{CE} = 10\text{V}_{DC}$ , $f = 20\text{MHz}$ )		fT	25	-	MHz
Output Capacitance ( $V_{CB} = 30\text{V}_{DC}$ , $I_E = 0\text{A}_{DC}$ , $f = 2.0\text{MHz}$ )		$C_{ob}$	-	40	pf
Turn On Time	(V <sub>CC</sub> = 330V <sub>DC</sub> , I <sub>C</sub> = 500mA <sub>DC</sub> , I <sub>B1</sub> = I <sub>B2</sub> = 100mA <sub>DC</sub> R <sub>B1</sub> = R <sub>B2</sub> = 330Ω)	t <sub>(on)</sub>	-	700	ns
Turn Off Time		t <sub>(off)</sub>	-	2000	ns

\*Pulse Test: Pulse Width = 300us, Duty Cycle = 2%